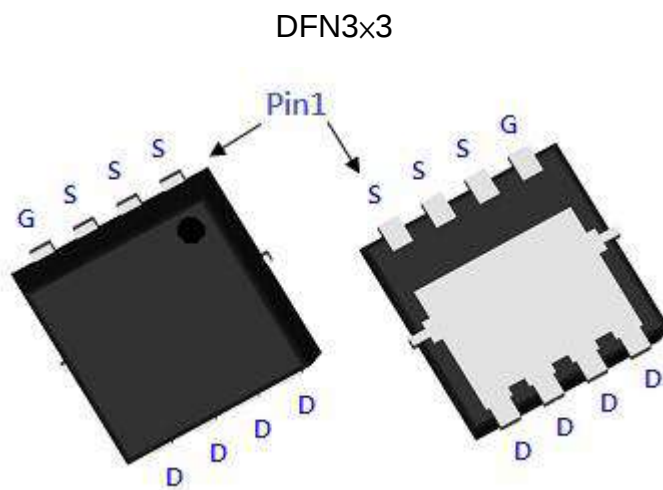


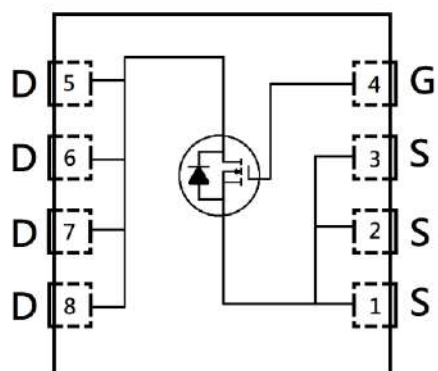
## N-Channel Enhancement Mode Power MOSFET

### Features:

- Simple drive requirement
- Low on-resistance
- Fast switching speed
- Pb-free lead plating package



|                                   |                       |
|-----------------------------------|-----------------------|
| $BV_{DSS}$                        | 30V                   |
| $I_D@T_C=25^{\circ}C, V_{GS}=10V$ | 111A                  |
| $I_D@T_A=25^{\circ}C, V_{GS}=10V$ | 19A                   |
| $R_{DS(ON)}@V_{GS}=10V, I_D=20A$  | 1.7 m $\Omega$ (typ.) |
| $R_{DS(ON)}@V_{GS}=4.5V, I_D=20A$ | 4.1 m $\Omega$ (typ.) |



G : Gate S : Source D : Drain

### Ordering Information

| Device      | Package                                                   | Shipping               |
|-------------|-----------------------------------------------------------|------------------------|
| KSPRB2D2N03 | DFN3x3<br>(Pb-free lead plating and halogen-free package) | 3000 pcs / Tape & Reel |

## Absolute Maximum Ratings (Ta=25°C)

| Parameter                                                              | Symbol                            | Limits   | Unit |
|------------------------------------------------------------------------|-----------------------------------|----------|------|
| Drain-Source Voltage                                                   | V <sub>DS</sub>                   | 30       | V    |
| Gate-Source Voltage                                                    | V <sub>GS</sub>                   | ±20      |      |
| Continuous Drain Current @ T <sub>C</sub> =25°C, V <sub>GS</sub> =10V  | I <sub>D</sub>                    | 111      | A    |
| Continuous Drain Current @ T <sub>C</sub> =100°C, V <sub>GS</sub> =10V |                                   | 70       |      |
| Continuous Drain Current @ T <sub>A</sub> =25°C, V <sub>GS</sub> =10V  |                                   | 19       |      |
| Continuous Drain Current @ T <sub>A</sub> =70°C, V <sub>GS</sub> =10V  |                                   | 15       |      |
| Pulsed Drain Current                                                   | I <sub>DM</sub>                   | 444 *1   | mJ   |
| Avalanche Current @ L=0.1mH                                            | I <sub>AS</sub>                   | 40       |      |
| Avalanche Energy @ L=0.5mH                                             | E <sub>AS</sub>                   | 156 *4   | W    |
| Total Power Dissipation                                                | T <sub>C</sub> =25°C              | 62       |      |
|                                                                        | T <sub>C</sub> =100°C             | 25       |      |
|                                                                        | T <sub>A</sub> =25°C              | 1.9 *3   |      |
|                                                                        | T <sub>A</sub> =70°C              | 1.2 *3   |      |
| Operating Junction and Storage Temperature Range                       | T <sub>J</sub> , T <sub>stg</sub> | -55~+150 | °C   |

## Thermal Data

| Parameter                                    | Symbol           | Value | Unit |
|----------------------------------------------|------------------|-------|------|
| Thermal Resistance, Junction-to-case, max    | R <sub>θJC</sub> | 2     | °C/W |
| Thermal Resistance, Junction-to-ambient, max | R <sub>θJA</sub> | 67 *3 |      |

Note : 1. Pulse width limited by maximum junction temperature  
2. Duty cycle ≤ 1%  
3. Surface mounted on 1 in<sup>2</sup> copper pad of FR-4 board, t ≤ 10s ; 125°C/W when mounted on minimum copper pad.

## Electrical Characteristics (T<sub>J</sub>=25°C, unless otherwise specified)

| Symbol                 | Min. | Typ. | Max. | Unit | Test Conditions                                                 |
|------------------------|------|------|------|------|-----------------------------------------------------------------|
| <b>Static</b>          |      |      |      |      |                                                                 |
| BV <sub>DSS</sub>      | 30   | -    | -    | V    | V <sub>GS</sub> =0V, I <sub>D</sub> =250μA                      |
| V <sub>GS(th)</sub>    | 1    | -    | 2.5  |      | V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA        |
| I <sub>GSS</sub>       | -    | -    | ±100 | nA   | V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V                      |
| I <sub>DSS</sub>       | -    | -    | 1    | μA   | V <sub>DS</sub> =24V, V <sub>GS</sub> =0V                       |
|                        | -    | -    | 5    |      | V <sub>DS</sub> =24V, V <sub>GS</sub> =0V, T <sub>j</sub> =55°C |
| R <sub>DS(ON)</sub> *1 | -    | 1.7  | 2.5  | mΩ   | V <sub>GS</sub> =10V, I <sub>D</sub> =20A                       |
|                        | -    | 4.1  | 6    |      | V <sub>GS</sub> =4.5V, I <sub>D</sub> =20A                      |
| G <sub>FS</sub> *1     | -    | 45   | -    | S    | V <sub>DS</sub> =5V, I <sub>D</sub> =20A                        |

## Electrical Characteristics(Cont.) (T<sub>J</sub>=25°C, unless otherwise specified)

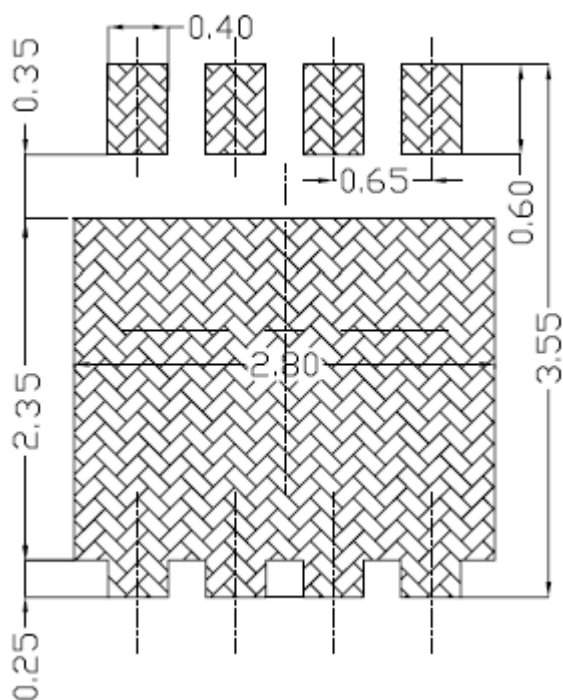
| Symbol                     | Min. | Typ. | Max. | Unit | Test Conditions                                                                       |
|----------------------------|------|------|------|------|---------------------------------------------------------------------------------------|
| <b>Dynamic</b>             |      |      |      |      |                                                                                       |
| Ciss                       | -    | 3400 | -    | pF   | V <sub>DS</sub> =15V, V <sub>GS</sub> =0V, f=1MHz                                     |
| Coss                       | -    | 445  | -    |      |                                                                                       |
| Crss                       | -    | 350  | -    |      |                                                                                       |
| Qg *1, 2                   | -    | 36   | -    | nC   | V <sub>DS</sub> =15V, I <sub>D</sub> =20A, V <sub>GS</sub> =4.5V                      |
| Qgs *1, 2                  | -    | 11   | -    |      |                                                                                       |
| Qgd *1, 2                  | -    | 18   | -    |      |                                                                                       |
| t <sub>d</sub> (ON) *1, 2  | -    | 18   | -    | ns   | V <sub>DS</sub> =15V, I <sub>D</sub> =20A, V <sub>GS</sub> =10V<br>R <sub>G</sub> =3Ω |
| t <sub>r</sub> *1, 2       | -    | 22   | -    |      |                                                                                       |
| t <sub>d</sub> (OFF) *1, 2 | -    | 72   | -    |      |                                                                                       |
| t <sub>f</sub> *1, 2       | -    | 16   | -    |      |                                                                                       |
| R <sub>g</sub>             | -    | 1.2  | -    | Ω    | f=1MHz                                                                                |
| <b>Source-Drain Diode</b>  |      |      |      |      |                                                                                       |
| I <sub>S</sub> *1          | -    | -    | 20   | A    |                                                                                       |
| I <sub>SM</sub> *3         | -    | -    | 80   |      |                                                                                       |
| V <sub>SD</sub> *1         | -    | 0.83 | 1.2  | V    | I <sub>F</sub> =10A, V <sub>GS</sub> =0V                                              |
| t <sub>rr</sub>            | -    | 18   | -    | ns   | I <sub>F</sub> =20A, dI <sub>F</sub> /dt=100A/μs                                      |
| Q <sub>rr</sub>            | -    | 12   | -    | nC   |                                                                                       |

Note : \*1.Pulse Test : Pulse Width ≤300μs, Duty Cycle≤2%

\*2.Independent of operating temperature

\*3.Pulse width limited by maximum junction temperature.

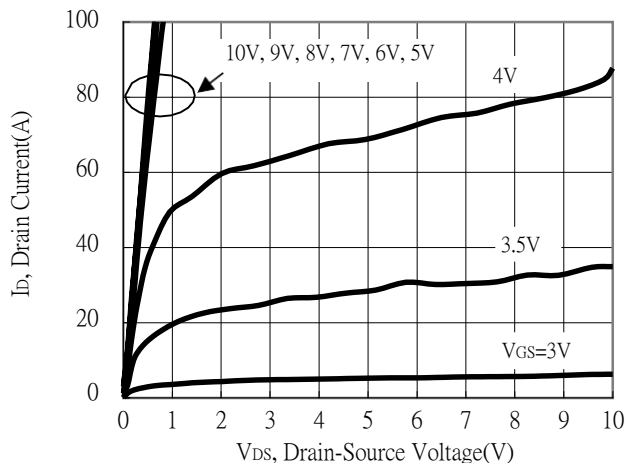
## Recommended Soldering Footprint



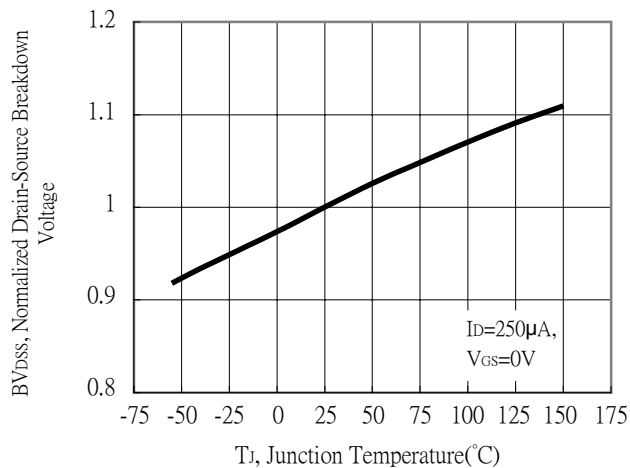
unit : mm

## Typical Characteristics

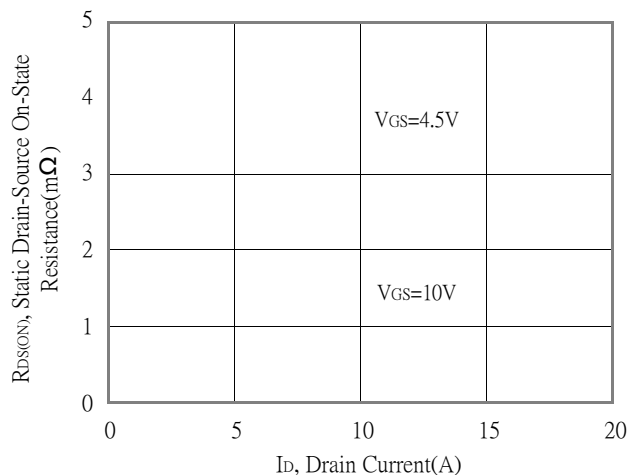
Typical Output Characteristics



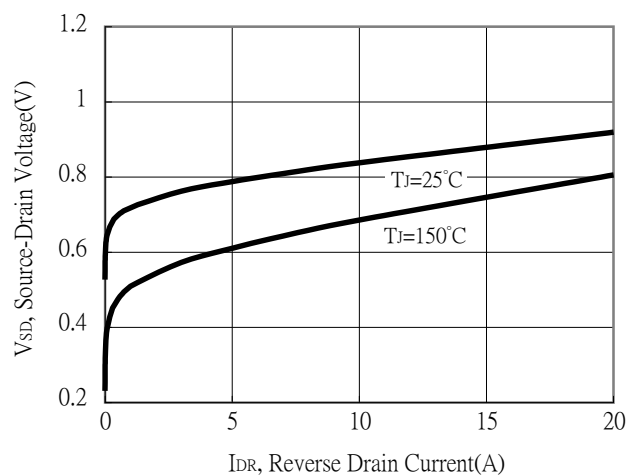
Breakdown Voltage vs Ambient Temperature



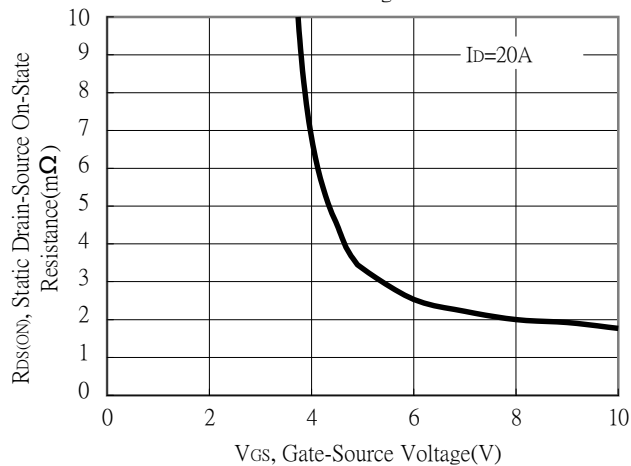
Static Drain-Source On-State resistance vs Drain Current



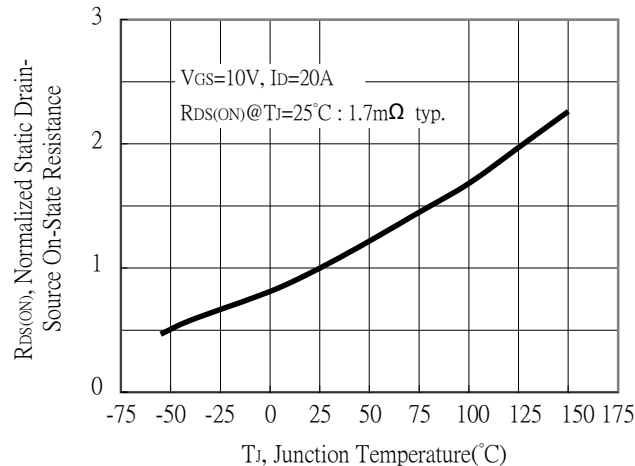
Reverse Drain Current vs Source-Drain Voltage



Static Drain-Source On-State Resistance vs Gate-Source Voltage

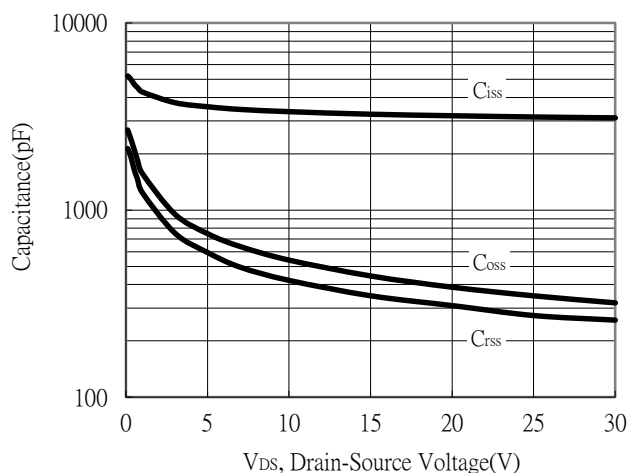


Drain-Source On-State Resistance vs Junction Temperature

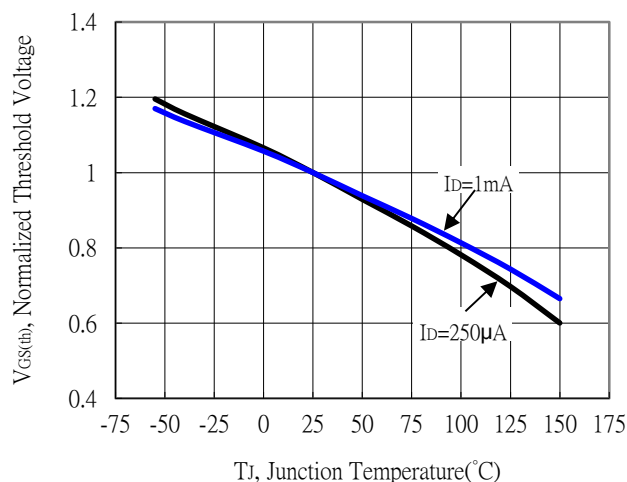


## Typical Characteristics(Cont.)

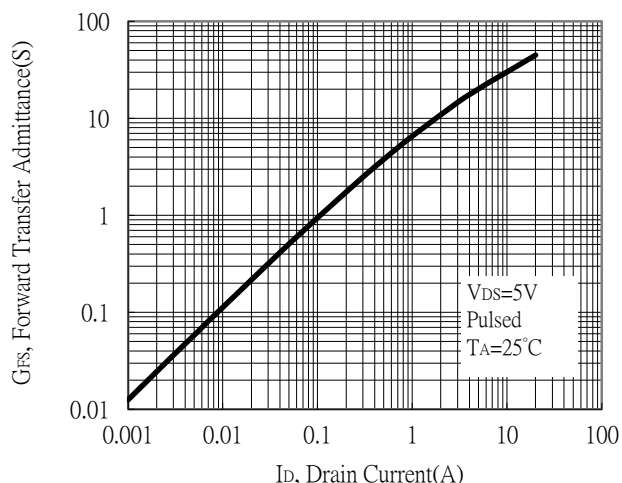
Capacitance vs Drain-to-Source Voltage



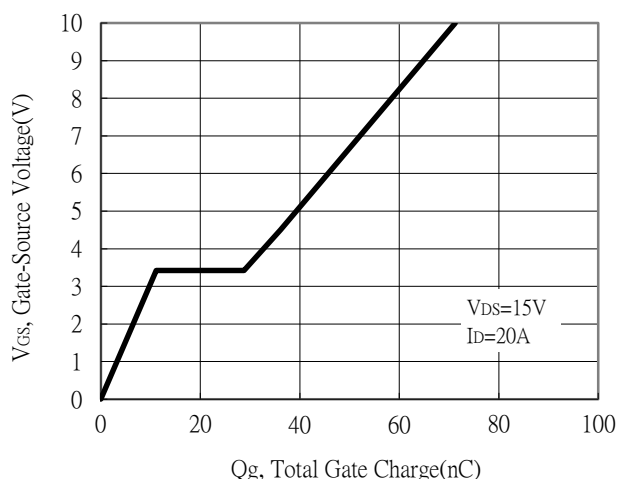
Threshold Voltage vs Junction Temperature



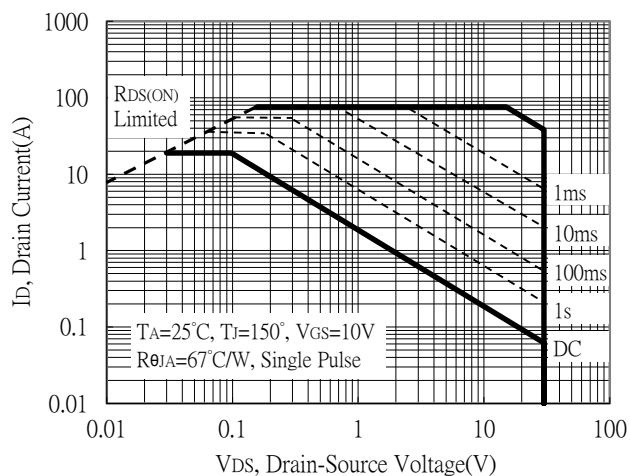
Forward Transfer Admittance vs Drain Current



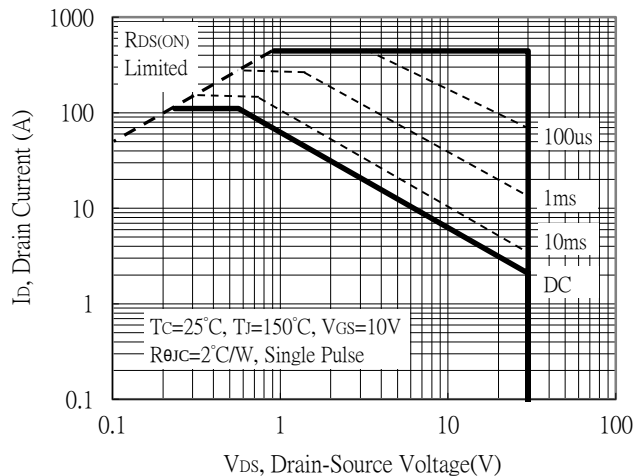
Gate Charge Characteristics



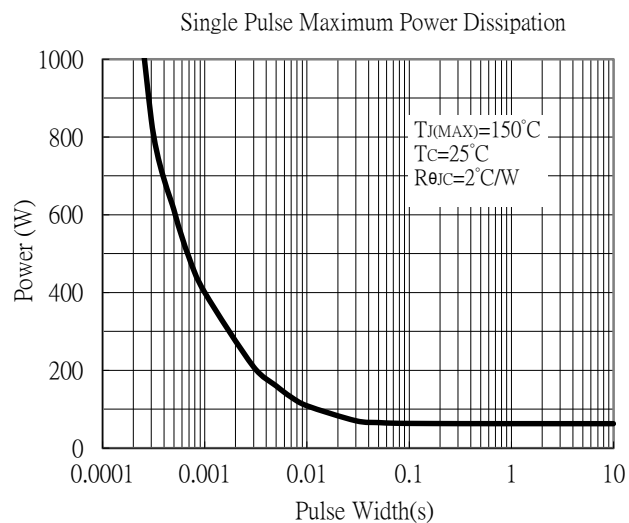
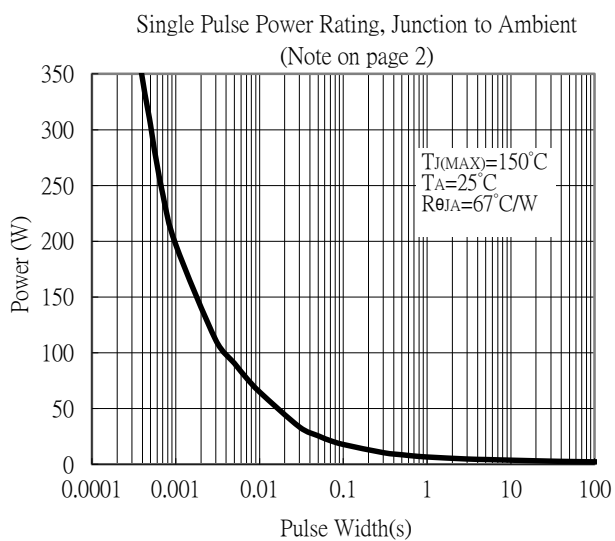
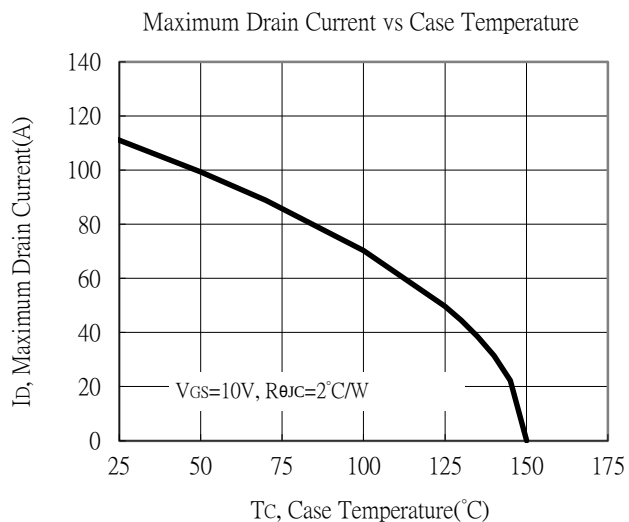
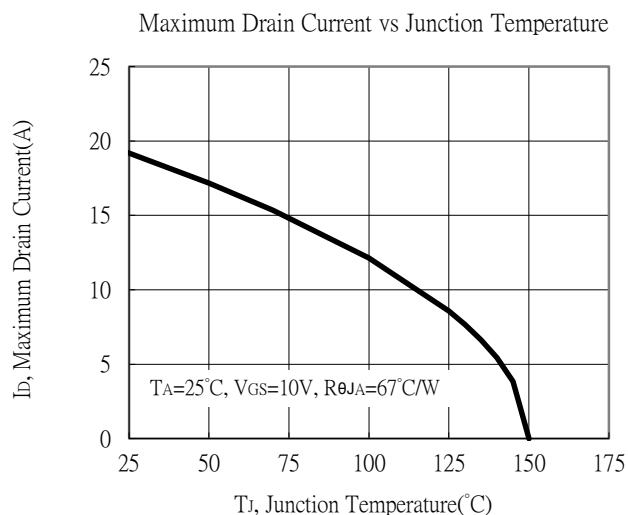
Maximum Safe Operating Area



Maximum Safe Operating Area

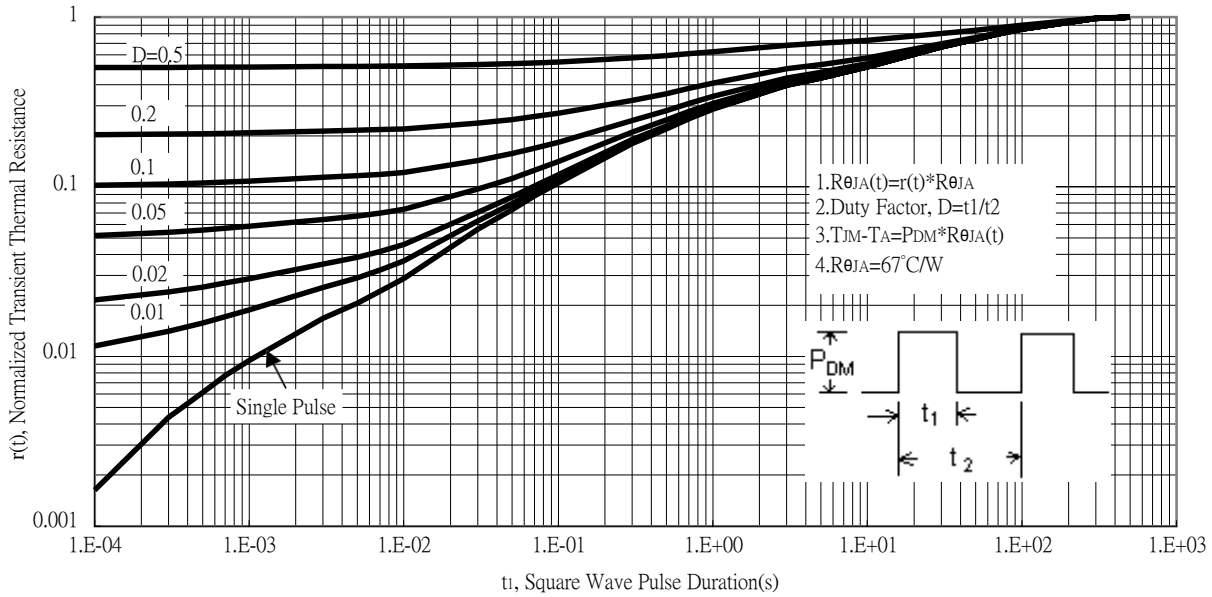


## Typical Characteristics(Cont.)

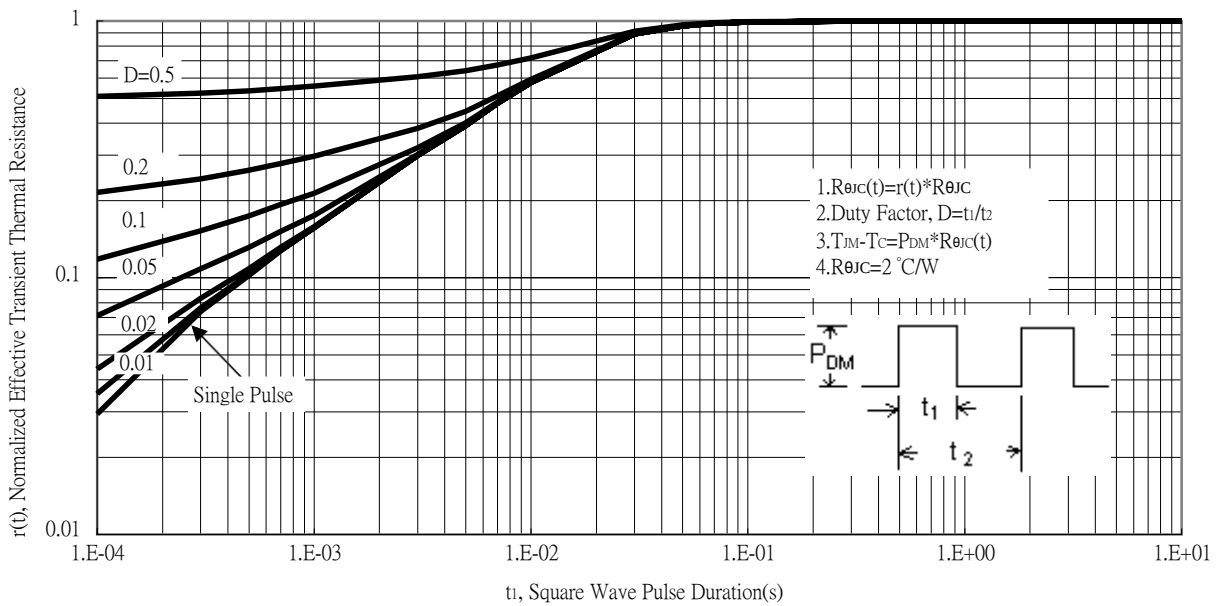


## Typical Characteristics(Cont.)

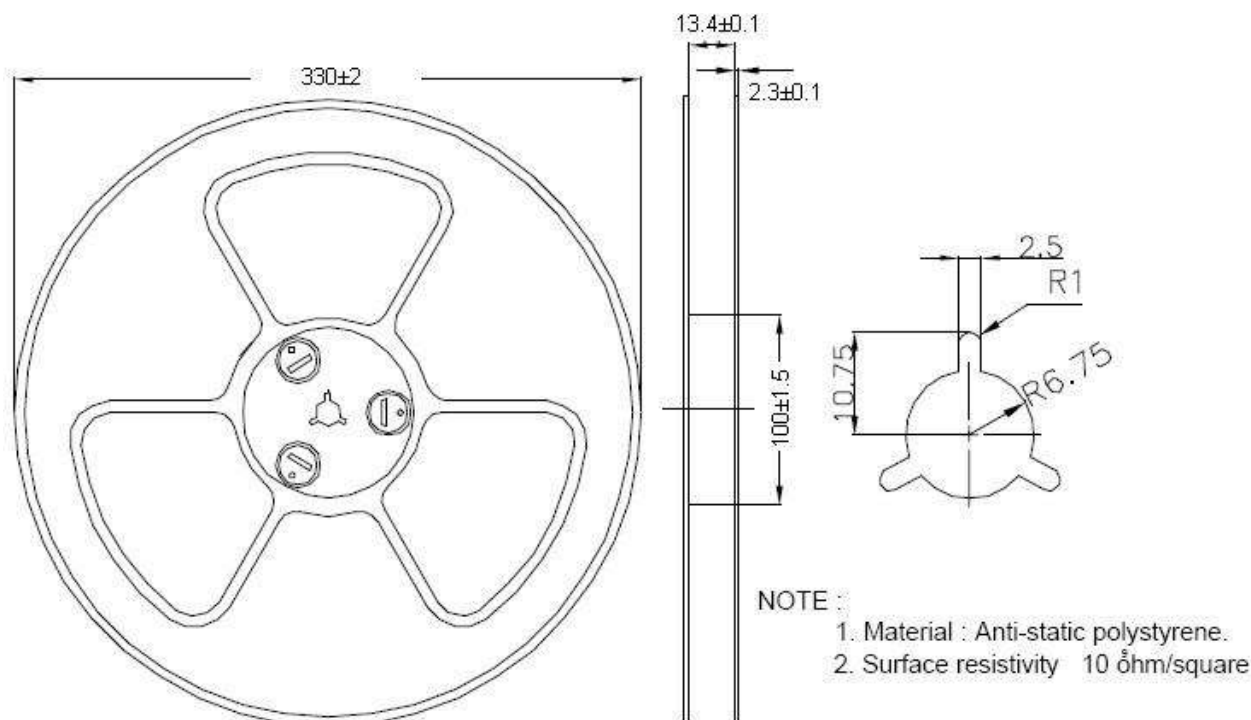
Transient Thermal Response Curves



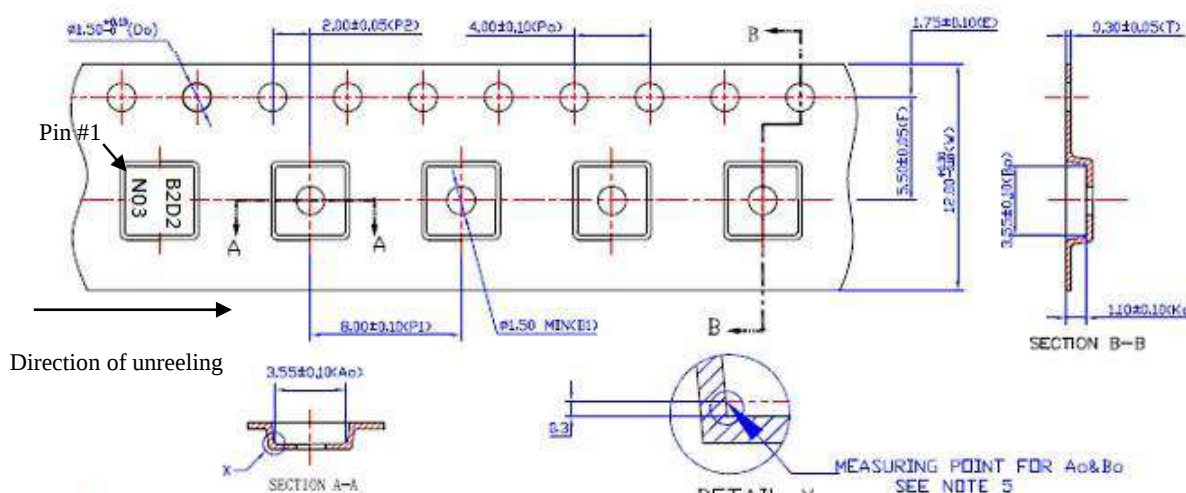
Transient Thermal Response Curves



## Reel Dimension



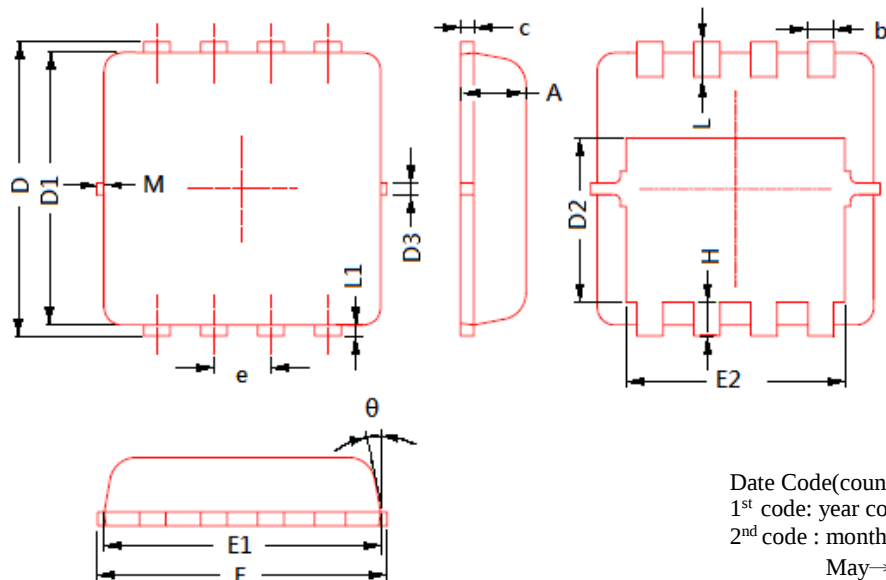
## Carrier Tape Dimension



Note :

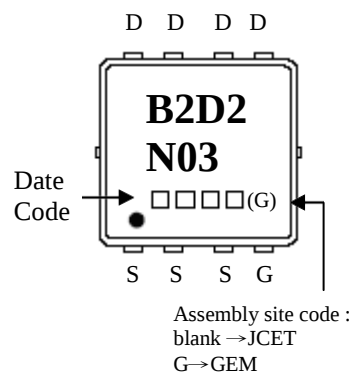
1. 10 sprocket hole pitch cumulative tolerance : ±0.2mm.
2. Camber : Reference to carrier tape inspection manual.
3. Material : black conductive polystyrene.
4. All dimensions are in millimeters (unless otherwise specified).
5. Ao and Bo measured on a plane 0.3mm above the bottom of the pocket.
6. Ko measured from a plane on the inside bottom of the pocket to the top surface of the carrier.
7. Pocket position relative to sprocket hole measured as true position of the pocket, not pocket hole.
8. Surface resistivity : 1×10<sup>4</sup>~1×10<sup>11</sup> ohms/sq

## DFN3x3 Dimension



8-Lead DFN3x3 Plastic Package

Marking:



Date Code(counting from left to right) :

1<sup>st</sup> code: year code, the last digit of Christian year

2<sup>nd</sup> code : month code, Jan→A, Feb→B, Mar→C, Apr→D

May→E, Jun→F, Jul→G, Aug→H, Sep→J,

Oct→K, Nov→L, Dec→M

3<sup>rd</sup> and 4<sup>th</sup> codes : production serial number, 01~99

| DIM | Millimeters |      | Inches    |       | DIM | Millimeters |      | Inches    |       |
|-----|-------------|------|-----------|-------|-----|-------------|------|-----------|-------|
|     | Min.        | Max. | Min.      | Max.  |     | Min.        | Max. | Min.      | Max.  |
| A   | 0.70        | 0.80 | 0.028     | 0.031 | E1  | 3.00        | 3.20 | 0.118     | 0.126 |
| b   | 0.25        | 0.35 | 0.010     | 0.014 | E2  | 2.39        | 2.59 | 0.094     | 0.102 |
| c   | 0.10        | 0.25 | 0.004     | 0.010 | e   | 0.65 BSC    |      | 0.026 BSC |       |
| D   | 3.25        | 3.45 | 0.128     | 0.136 | H   | 0.30        | 0.50 | 0.012     | 0.020 |
| D1  | 3.00        | 3.20 | 0.118     | 0.126 | L   | 0.30        | 0.50 | 0.012     | 0.020 |
| D2  | 1.78        | 1.98 | 0.070     | 0.078 | L1  | 0.13 TYP    |      | 0.005 TYP |       |
| D3  | 0.13 TYP    |      | 0.005 TYP |       | θ   | -           | 12°  | -         | 12°   |
| E   | 3.20        | 3.40 | 0.126     | 0.134 | M   | -           | 0.15 | -         | 0.006 |